

isc Silicon NPN Power Transistor

DESCRIPTION

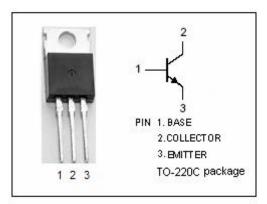
- · Low Collector Saturation Voltage
- : V_{CE(sat)}= 1.0V(Max)@I_C= 2A
- · Wide Area of Safe Operation
- · Complement to Type 2SB1064
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

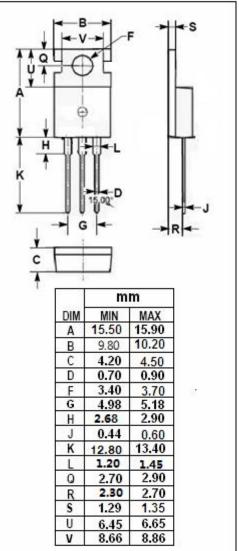
APPLICATIONS

• Designed for low frequency power amplifier applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	60	V	
VCEO	Collector-Emitter Voltage	50	V	
V _{EBO}	Emitter-Base Voltage	5	V	
Ic	Collector Current-Continuous	3	А	
I _{CM}	Collector Current-Peak	4.5	А	
P _C	Total Power Dissipation @ T _a =25℃	1.5	W	
	Total Power Dissipation @ T _C =25℃	30		
TJ	Junction Temperature 150		$^{\circ}$ C	
T _{stg}	Storage Temperature Range -55~1		$^{\circ}$	







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2SD1505

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 1mA; I _B = 0	50			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 50 μ A; I _E = 0	60			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 50 μ A; I _C = 0	5			V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 2A; I _B = 0.2A			1.0	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = 2A; I _B = 0.2A			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 40V; I _E = 0			1.0	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = 4V; I _C = 0			1.0	μА
h _{FE}	DC Current Gain	I _C = 0.5A; V _{CE} = 3V	60		320	
f _T	Current-Gain—Bandwidth Product	I _C = 0.5A; V _{CE} = 5V		90		MHz
Сов	Output Capacitance	I _E =0; V _{CB} = 10V; f= 1MHz		40		pF

♦ h_{FE} Classifications

D	E	F
60-120	100-200	160-320

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